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Vishay Siliconix

## P-Channel 40 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A) <sup>d</sup>		
-40	$0.0042 \text{ at V}_{GS} = -10 \text{ V}$	-110		
-40	0.0062 at V <sub>GS</sub> = -4.5 V	-110		

#### **FEATURES**

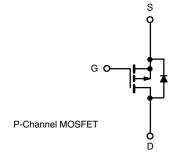
- TrenchFET® Power MOSFET
- Low thermal resistance











### **Ordering Information:**

SUM110P04-04L-E3 (Lead (Pb)-free)

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage	V <sub>DS</sub>	-40	V		
Gate-Source Voltage	V <sub>GS</sub>	± 20	v		
Continuous Drain Current (T,I = 175 °C) d	T <sub>C</sub> = 25 °C		-110	А	
Continuous Drain Current (1) = 175 C) °	T <sub>C</sub> = 125 °C	l l <sup>D</sup>	-110		
Pulsed Drain Current	I <sub>DM</sub>	-240	_ A		
Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	-75		
Single Pulse Avalanche Energy <sup>a</sup>	L = 0.1 IIII	E <sub>AS</sub>	281	mJ	
Dower Discinstion	T <sub>C</sub> = 25 °C	PD	375 <sup>c</sup>	W	
Power Dissipation	T <sub>A</sub> = 25 °C b		3.75	vv	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-Ambient PCB Mount <sup>b</sup>	R <sub>thJA</sub>	40	°C/W		
Junction-to-Case	$R_{thJC}$	0.4			

#### Notes

- a. Duty cycle ≤ 1 %.
- b. When mounted on 1" square PCB (FR-4 material).
- c. See SOA curve for voltage derating.
- d. Limited by package.



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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static	•						
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-40				
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	-1		-3	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
		V <sub>DS</sub> = -40 V, V <sub>GS</sub> = 0 V			-1	μА	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = -40 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125 °C			-50		
		V <sub>DS</sub> = -40 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 175 °C			-250		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-120			Α	
		V <sub>GS</sub> = -10 V, I <sub>D</sub> = -30 A		0.0034	0.0042	Ω	
Drain Cauras On State Besistance 3		V <sub>GS</sub> = -10 V, I <sub>D</sub> = -30 A, T <sub>J</sub> = 125 °C			0.0063		
Drain-Source On-State Resistance a	R <sub>DS(on)</sub>	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -30 A, T <sub>J</sub> = 175 °C			0.0076		
		$V_{GS} = -4.5 \text{ V}, I_D = -20 \text{ A}$		0.005	0.0062		
Forward Transconductance <sup>a</sup>	9fs	V <sub>DS</sub> = -15 V, I <sub>D</sub> = -30 A	20			S	
Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>			11 200		pF	
Output Capacitance	Coss	$V_{GS} = 0 \text{ V}, V_{DS} = -25 \text{ V}, f = 1 \text{ MHz}$		1650			
Reverse Transfer Capacitance	C <sub>rss</sub>			1200			
Total Gate Charge <sup>c</sup>	Qg			235	350		
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = -20 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -110 \text{ A}$		45		nC	
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$			65			
Gate Resistance	$R_g$			3		Ω	
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			25	40		
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = -20 \text{ V}, R_1 = 0.18 \Omega$		30	45		
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong -110 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 2.5 \Omega$		190	300	ns	
Fall Time <sup>c</sup>	t <sub>f</sub>			110	165		
Source-Drain Diode Ratings and Cha	racteristics	(T <sub>C</sub> = 25 °C) <sup>b</sup>					
Continuous Current	I <sub>S</sub>				-110	^	
Pulsed Current	I <sub>SM</sub>				-240	Α	
Forward Voltage <sup>a</sup>	$V_{SD}$	$I_F = -85 \text{ A}, V_{GS} = 0 \text{ V}$		-1	-1.5	V	
Reverse Recovery Time	t <sub>rr</sub>			65	100	ns	
Peak Reverse Recovery Current	I <sub>RM(REC)</sub>	I <sub>F</sub> = -85 A, dl/dt = 100 A/μs		-3.7	-5.6	Α	
Reverse Recovery Charge	Q <sub>rr</sub>			0.12	0.28	μC	

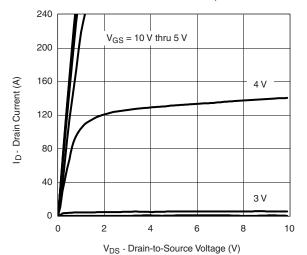
#### Notes

- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

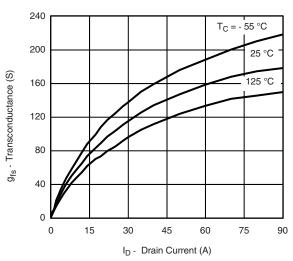
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



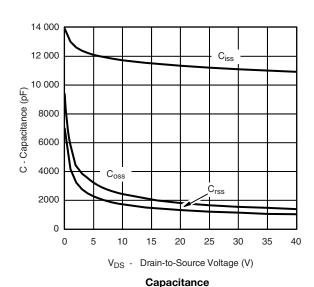
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

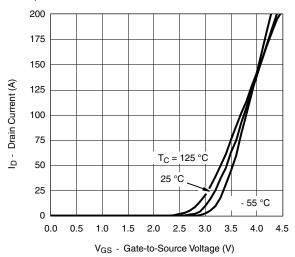


### **Output Characteristics**

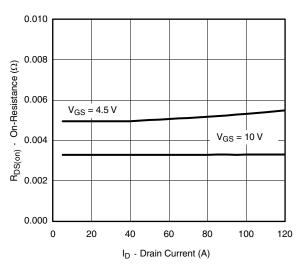


### Transconductance

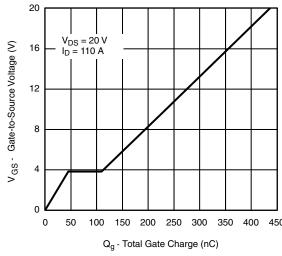




#### **Transfer Characteristics**

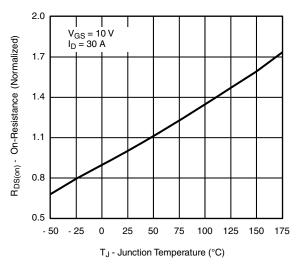


### On-Resistance vs. Drain Current

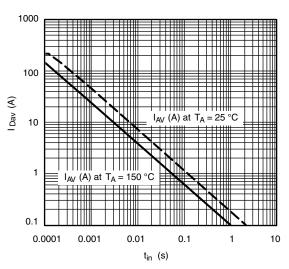




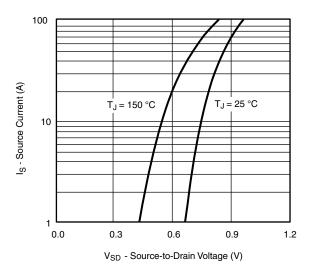
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



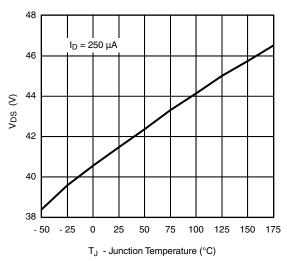
#### On-Resistance vs. Junction Temperature



Avalanche Current vs. Time



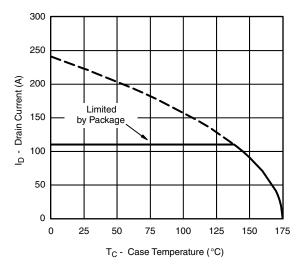
Source-Drain Diode Forward Voltage



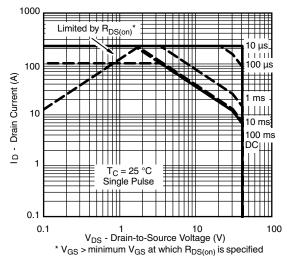
**Drain Source Breakdown vs. Junction Temperature** 



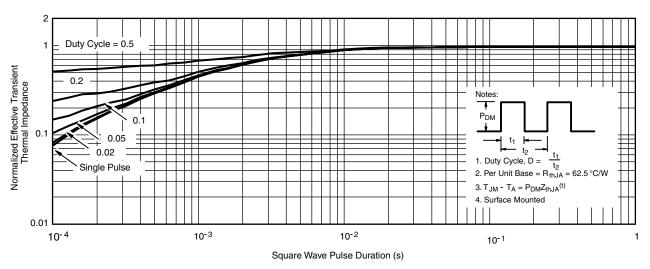
### THERMAL RATINGS



Maximum Avalanche and Drain Current vs. Case Temperature



Safe Operating Area

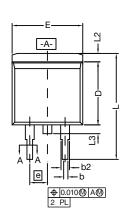


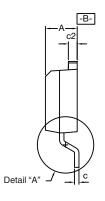
Normalized Thermal Transient Impedance, Junction-to-Case

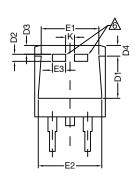
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# TO-263 (D<sup>2</sup>PAK): 3-LEAD

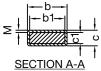








DETAIL A (ROTATED 90°)



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- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. \*: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6. This feature is for thick lead.

		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
Α		0.160	0.190	4.064	4.826	
b		0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	Е	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	=	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829	1.981	
е		0.100	) BSC	2.54 BSC		
K		0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
L4		0.010 BSC		0.254 BSC		
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13						

DWG: 5843





### RECOMMENDED MINIMUM PADS FOR D<sup>2</sup>PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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